

Discrete IGBTs Silicon N-Channel IGBT

GT40RR21

1. Applications

• Dedicated to Voltage-Resonant Inverter Switching Applications

Note: The product(s) described herein should not be used for any other application.

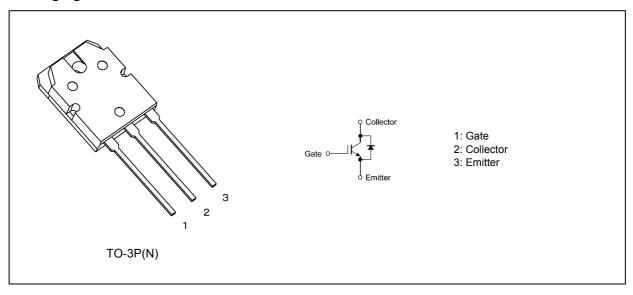
2. Features

- (1) 6.5th generation
- (2) The RC-IGBT consists of a freewheeling diode monolithically integrated in an IGBT chip.
- (3) Enhancement mode
- (4) High-speed switching

IGBT : $t_f = 0.21 \mu s$ (typ.) ($I_C = 40 A$) FWD : $t_{rr} = 0.60 \mu s$ (typ.) ($I_F = 15 A$)

- (5) Low saturation voltage : $V_{CE(sat)} = 2.05 \text{ V (typ.)}$ ($I_C = 40 \text{ A}$)
- (6) High junction temperature : $T_j = 175^{\circ}C$ (max)

3. Packaging and Internal Circuit





4. Absolute Maximum Ratings (Note) (Ta = 25°C, unless otherwise specified)

Characteristics			Symbol	Rating	Unit
Collector-emitter voltage			V _{CES}	1350	V
Gate-emitter voltage			V _{GES}	±25	1
Collector current (DC)	(T _c = 25°C)		I _C	40	Α
Collector current (DC)	(T _c = 100°C)			33	1
Collector current (3 μs)			I _{CP}	200	1
Collector current (1 ms)				80	1
Diode forward current (DC)			I _F	20	1
Diode forward current (100 μs)			I _{FP}	80	1
Collector power dissipation	(T _c = 25°C)		P _C	230	W
Junction temperature		(Note 1)	Tj	175	°C
Storage temperature			T _{stg}	-55 to 175	1
Mounting torque			TOR	0.8	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

In general, loss of IGBT increases more when it has positive temperature coefficient and gets higher temperature.

In case that the temperature rise due to loss of IGBT exceeds the heat release capacity of a device, it leads to thermorunaway and results in destruction.

Therefore, please design heat release of a device with due consideration to the temperature rise of IGBT.

Note 1: Ensure that the junction temperature does not exceed 175°C.

5. Thermal Characteristics

Characteristics		Max	Unit
Junction-to-case thermal resistance		0.65	°C/W



6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25°C, unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GES}	$V_{GE} = \pm 25 \text{ V}, V_{CE} = 0 \text{ V}$	_	_	±100	nA
Collector cut-off current	I _{CES}	V _{CE} = 1350 V, V _{GE} = 0 V			1.0	mA
Gate-emitter cut-off voltage	V _{GE(OFF)}	I_C = 40 mA, V_{CE} = 5 V	4.5		7.5	V
Collector-emitter saturation voltage	V _{CE(sat)(1)}	I _C = 20 A, V _{GE} = 15 V		1.60		
Collector-emitter saturation voltage	V _{CE(sat)(2)}	$I_C = 20 \text{ A}, V_{GE} = 15 \text{ V},$ $T_j = 125^{\circ}\text{C}$	_	1.85	_	
Collector-emitter saturation voltage	V _{CE(sat)(3)}	$I_C = 20 \text{ A}, V_{GE} = 15 \text{ V},$ $T_j = 175^{\circ}\text{C}$	_	2.00	_	
Collector-emitter saturation voltage	V _{CE(sat)(4)}	I _C = 40 A, V _{GE} = 15 V	_	2.05	2.80	
Collector-emitter saturation voltage	V _{CE(sat)(5)}	I _C = 40 A, V _{GE} = 15 V, T _j = 125°C	_	2.45	_	
Collector-emitter saturation voltage	V _{CE(sat)(6)}	I_C = 40 A, V_{GE} = 15 V, T_j = 175°C	_	2.70	_	
Diode forward voltage	V_{F}	I _F = 15 A, V _{GE} = 0 V	_	1.75	2.80	



6.2. Dynamic Characteristics (T_a = 25°C, unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{ies}	V _{CE} = 10 V, V _{GE} = 0 V, f = 1 MHz	_	1500		pF
Switching time (rise time)	t _r	Resistive load		0.12		μS
Switching time (turn-on time)	t _{on}	$V_{CC} = 600 \text{ V}, I_{C} = 40 \text{ A},$ $V_{GG} = \pm 15 \text{ V}, R_{G} = 39 \Omega$	_	0.20		
Switching time (fall time)	t _f	See Fig. 6.2.1, 6.2.2.	_	0.21	0.40	
Switching time (turn-off time)	t _{off}		_	0.40	_	
Switching loss (turn-off switching loss)	E _{off(1)}	Inductive Load V_{CC} = 280 V, I_{C} = 40 A, L = 30 μ H, C = 0.33 μ F, V_{GG} = 20 V, R_{G} = 10 Ω See Fig. 6.2.3, 6.2.4.		0.28		mJ
Switching loss (turn-off switching loss)	E _{off(2)}	Inductive Load $V_{CC} = 280 \text{ V, } I_{C} = 40 \text{ A,} \\ L = 30 \mu\text{H,C} = 0.33 \mu\text{H,} \\ V_{GG} = 20 \text{ V, } R_{G} = 10 \Omega \\ T_{c} = 125^{\circ}\text{C}$ See Fig. 6.2.3, 6.2.4.	_	0.54		
Reverse recovery time	t _{rr}	$I_F = 15 \text{ A}, V_{GE} = 0 \text{ V},$ di/dt = -20 A/ μ s	-	0.60	ı	μS

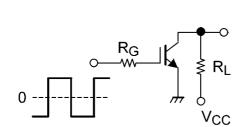


Fig. 6.2.1 Test Circuit of Switching Time

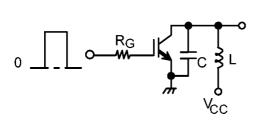


Fig. 6.2.3 Test Circuit of Switching Loss

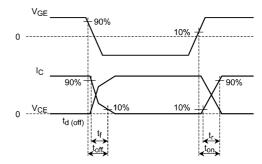


Fig. 6.2.2 Timing Chart of Switching Time

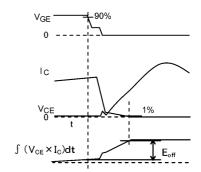


Fig. 6.2.4 Timing Chart of Switching Loss



7. Marking (Note)

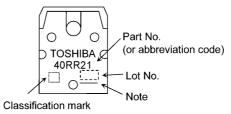


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

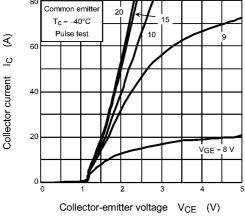
The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

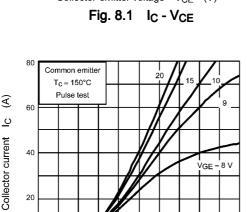
Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

3

Collector current

8. Characteristics Curves (Note)





Collector-emitter voltage V_{CE} (V) Fig. 8.3 I_C - V_{CE}

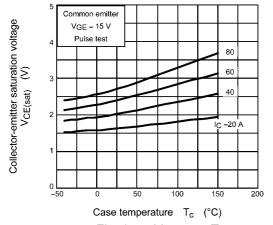


Fig. 8.5 V_{CE(sat)} - T_c

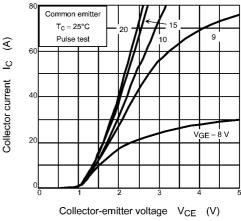


Fig. 8.2 Ic - VCE

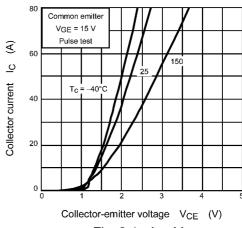


Fig. 8.4 I_C - V_{CE}

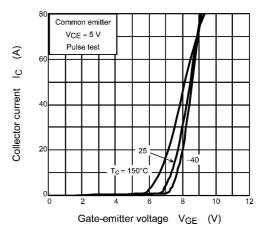


Fig. 8.6 Ic - VGE

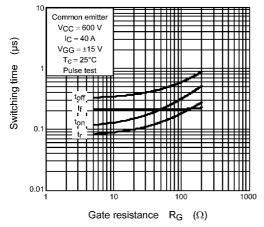


Fig. 8.7 Switching Time - R_G

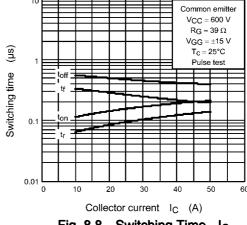


Fig. 8.8 Switching Time - I_C

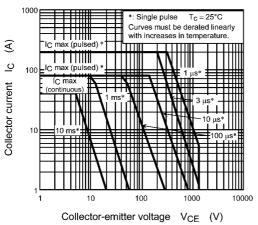


Fig. 8.9 Safe Operating Area (Guaranteed Maximum)

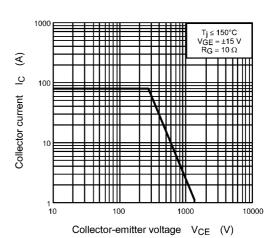


Fig. 8.10 Reverse Bias SOA (Guaranteed Maximum)

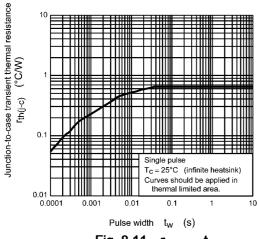
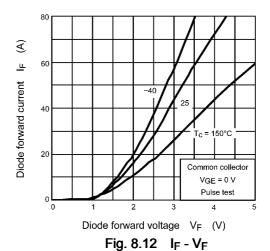


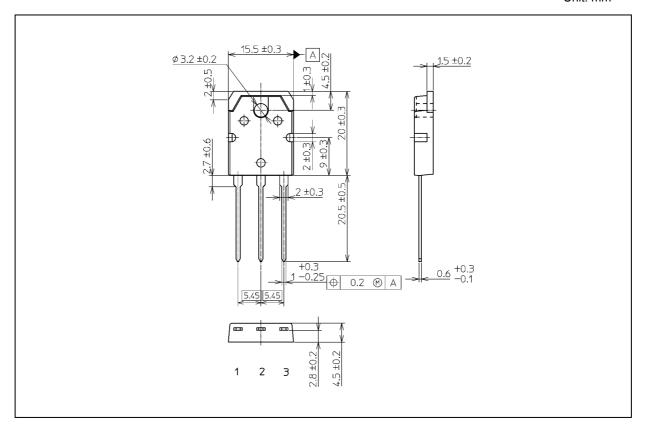
Fig. 8.11 $r_{th(j-c)} - t_w$ (Guaranteed Maximum)



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 4.6 g (typ.)

	Package Name(s)
TOSHIBA: 2-16C1S	
Nickname: TO-3P(N)	



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